NSN 5961-01-516-4962

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-516-4962 **Inclosure Material:** Plastic **Overall Length:** Between 0.189 inches and 0.197 inches **Overall Height:** Between 0.053 inches and 0.069 inches Overall Width: Between 0.228 inches and 0.244 inches **End Application:** General purpose electronic test equipment gpete; 6625-01-462-7491. Joint Electronic Device Engineering Council/jedec/case Outline Designation: So-8 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 4.8 reverse breakdown voltage, dc and 5.2 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 15.00 milliamperes forward current, average peak and 10.00 milliamperes source cutoff current preset **Product Name:** 5.0v reference diode **Special Features:** Gullwing leads **Terminal Type And Quantity:** 8 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No